

Q.CELLS
YIELD SECURITY

- ✓ ANTI PID TECHNOLOGY (APT)
- ✓ ADDITIONAL POWER BOOST (APB)
- ✓ 360° EFFICIENCY (TDE)

CIGS SOLAR MODULE

Q.SMART UF L 95-1 15

Generation 1.3 - Efficiency and esthetics have a new name

With up to 13.4 %, our CIGS solar modules of the **Q.SMART** series are the most efficient thin-film modules on the market. The outstanding low-light behaviour as well as the extra power due to positive sorting and light soaking effect make them ideal for challenging installations. **Q.SMART UF L** is our space wonder for commercial and industrial flat roofs and facades.

THE NEW Q-CELLS GENERATION

- World's best efficiencies up to 13.4 %:
Highest yields per installed area.
- Anti PID Technology (APT)¹: **No power loss caused by potential induced degradation.**
- Outstanding low-light behaviour for 360° Efficiency (TDE): **High yields even in challenging roof expositions - north, west, south or east.**

THE PROVEN Q-CELLS VALUES

- Additional Power Boost (APB) with up to 15 % additional output due to positive sorting (+5 / -0W) and light soaking effect:
More power for your money.
- Increased module surface (0.94 m²):
Optimal utilization of flat roofs.
- Frameless Design: **Ideal for roof-parallel installations on flat roofs.**
- 25 years linear performance warranty, 10 years product warranty², even for installations < 30 kWp: **Secure investment.**



THE IDEAL
SOLUTION FOR:



ROOF-PARALLEL FLAT
ROOF INSTALLATIONS



IN-ROOF / ROOFTOP ARRAYS
ON COMMERCIAL /
INDUSTRIAL BUILDINGS

¹ APT test conditions: Cells at -600 V relative to frame, wet module surface, 25 °C, 300 h

² Performance warranty: min. 100 % of nominal power in the first 3 years; max. 0.7 % degradation per year from year 4; min. 85 % of nominal power after 25 years. Full product and performance warranties in accordance with the valid regional warranty terms.

Q.CELLS

MECHANICAL SPECIFICATION		TECHNICAL DRAWING
Length	1190 (+3/-1) mm	
Width	789.5 (+3/-1) mm	
Height	7.3 mm (+ Junction box, 15 mm)	
Weight	16.5 kg	
Front Cover	4 mm tempered low iron glass	
Back Cover	3 mm float glass	
Frame	None	
Cell Type	CIGS [Cu(In, Ga) Se ₂]	
Junction box	Protection class IP 65, with 1 bypass diode (3 A) 66 x 54 x 15 mm ³	
Cable type	Solar cable 2.5 mm ² ; (+) 855 (+30/-0) mm; (-) 735 (+30/-0) mm	
Connector	MC4	

ELECTRICAL CHARACTERISTICS

PERFORMANCE AT STANDARD TEST CONDITIONS (STC: 1000 W/m², 25 °C, AM 1.5 SPECTRUM)¹

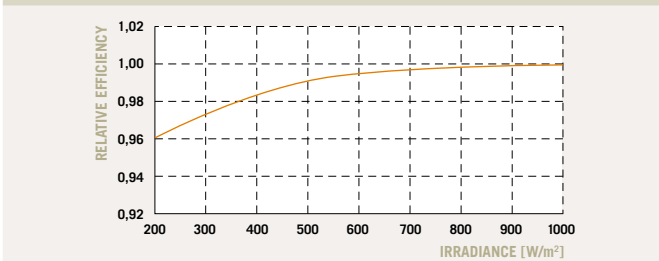
POWER CLASS			95	100	105	110	115
Nominal Power (+5/-0 Wp)	P _{MAX}	[W]	95.0	100.0	105.0	110.0	115.0
Short Circuit Current	I _{SC}	[A]	1.68	1.68	1.68	1.69	1.69
Open Circuit Voltage	V _{OC}	[V]	89.0	90.1	91.6	93.3	95.1
Current at Maximum Power	I _{MPP}	[A]	1.43	1.46	1.49	1.52	1.54
Voltage at Maximum Power	V _{MPP}	[V]	66.4	68.5	70.5	72.4	74.7
Nominal Efficiency	η	[%]	≥10.1	≥10.6	≥11.2	≥11.7	≥12.2

PERFORMANCE AT NORMAL OPERATING CELL TEMPERATURE (NOCT: 800 W/m², 51 ± 2 °C, AM 1.5 SPECTRUM)

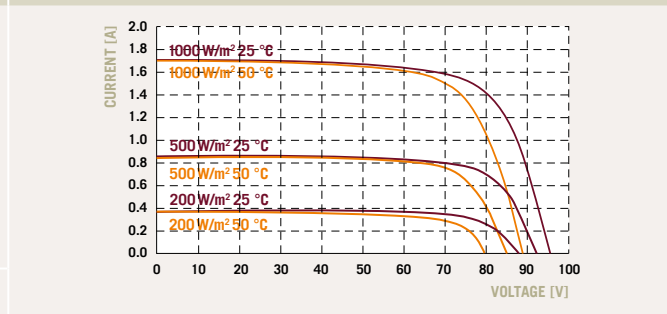
POWER CLASS			95	100	105	110	115
Nominal Power	P _{MAX}	[W]	68.7	72.3	75.9	79.5	83.1
Short Circuit Current	I _{SC}	[A]	1.34	1.34	1.34	1.35	1.35
Open Circuit Voltage	V _{OC}	[V]	81.0	82.0	83.4	84.9	86.5
Current at Maximum Power	I _{MPP}	[A]	1.14	1.16	1.18	1.21	1.22
Voltage at Maximum Power	V _{MPP}	[V]	60.2	62.1	64.0	65.7	67.8

¹ Measurement accuracy P_{MPP}: ± 5%; measurement accuracy I_{SC}, V_{OC}, I_{MPP}, V_{MPP}: ± 10 %. All STC measurements based on pre-treatment of modules with 1 hour light soak (1000 W/m² [1 kWh/m²], in open circuit) followed by cool down to 25 °C. For the system conception, please take into account the typical relative V_{OC} and V_{MPP} power increase of 2.5 % after 215 kWh/m² light soaking. This power boost is not included in the nominal values of this data sheet.

PERFORMANCE AT LOW IRRADIANCE CHARACTERISTICS AT DIFFERENT TEMPERATURES AND IRRADIANCES



The typical relative change in module efficiency (at nominal power) at an irradiance of 200 W/m² in relation to 1000 W/m² (both at 25 °C and AM 1.5 spectrum) is -4.0 % rel.



TEMPERATURE COEFFICIENTS (AT 1000 W/m², AM 1.5 SPECTRUM)

Temperature Coefficient of I _{SC}	α	[%/K]	+ 0.00 ± 0.04	Temperature Coefficient of V _{OC}	β	[%/K]	- 0.29 ± 0.04
Temperature Coefficient of P _{MAX}	γ	[%/K]	- 0.38 ± 0.04				

PROPERTIES FOR SYSTEM DESIGN

Maximum System Voltage V _{sys}	[V]	1000 (IEC) / 600 (UL 1703)	Safety Class	II
Maximum Reverse Current I _r	[A]	5.1	Fire Rating	C
Wind/Snow Load	[Pa]	2400	Permitted module temperature on continuous duty	-40 °C up to +85 °C

QUALIFICATIONS AND CERTIFICATES PARTNER

IEC 61646 (Ed. 2), IEC 61730 (Ed. 1) Application Class A, UL 1703
The production site is certified according to ISO 9001 for Quality Management.



Content of this data sheet according to DIN EN 50380.

PARTNER

NOTE: Installation instructions must be followed. See the installation and operating manual or contact the technical service for further information on approved installation and use of this product.